## **General Specifications**





#### **GENERAL DESCRIPTION**

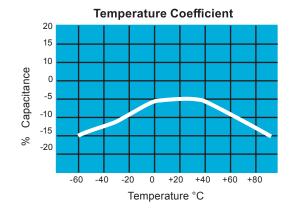
- · General Purpose Dielectric for Ceramic Capacitors
- EIA Class II Dielectric
- Temperature variation of capacitance is within ±15% from -55°C to +85°C
- Well suited for decoupling and filtering applications
- Available in High Capacitance values (up to 100μF)

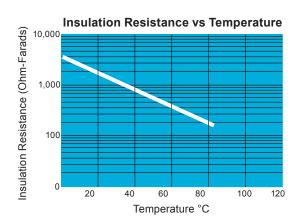
### PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

1210	4	D	107	M	Α	T	2	Α
	T	T	T	T	T	T	T	T
Size	Voltage	Dielectric	Capacitance	Capacitance	Failure	Terminations	Packaging	Special
(L" x W")	4 = 4V	D = X5R	Code (In pF)	Tolerance	Rate	T = Plated Ni	2 = 7" Reel	Code
0101**	6 = 6.3V		2 Sig. Digits +	$K = \pm 10\%$	A = N/A	and Sn	4 = 13" Reel	A = Std.
0201	Z = 10V		Number of	$M = \pm 20\%$				
0402	Y = 16V		Zeros					
0603	3 = 25V							
0805	D = 35V							<b>A</b> .
1206	5 = 50V							
1210	1 = 100V							The same of the sa
1812								
**EIA 010	05							RoHS
								COMPLIANT

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

### TYPICAL ELECTRICAL CHARACTERISTICS









Parame	ter/Test	X5R Specification Limits	Measuring C	onditions					
Operating Tem		-55°C to +85°C	Temperature Cycle Chamber						
Capac Dissipati	itance on Factor	Within specified tolerance  ≤ 2.5% for ≥ 50V DC rating  ≤ 12.5% for 25V, 35V DC rating  ≤ 12.5% Max. for 16V DC rating and lower  Contact Factory for DF by PN	Freq.: 1.0 kHz ± 10% Voltage: 1.0Vrms ± .2V For Cap > 10 μF, 0.5Vrms @ 120Hz						
Insulation	Resistance	10,000MΩ or 500MΩ - μF, whichever is less	Charge device with rate secs @ room te						
Dielectric	Strength	No breakdown or visual defects	Charge device with 250% seconds, w/charge and disto 50 mA	scharge current limited					
	Appearance	No defects	Deflection	: 2mm					
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 30	) seconds 1mm/sec					
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)							
	Insulation Resistance	≥ Initial Value x 0.3	90 m	m					
Solder	ability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic sold ± 0.5 sec						
	Appearance	No defects, <25% leaching of either end terminal							
	Capacitance Variation	≤ ±7.5%							
Resistance to Solder Heat  Dissipation Factor  Insulation Resistance		Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60seconds. Store at room temperature for 24 ± 2hours before measuring electrical properties.						
		Meets Initial Values (As Above)	2hours before measuring	j electrical properties.					
	Dielectric Strength	Meets Initial Values (As Above)							
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes					
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes					
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes					
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes					
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and measure after 24 ± 2 hours at room temperature						
	Appearance	No visual defects	Charge device with 1.5X	rated voltage in test					
	Capacitance Variation	≤ ±12.5%	chamber set at 85°C ± (+48, -	2°C for 1000 hours					
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	Note: Contact factory for part numbers that are to						
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	voltaç						
	Dielectric Strength	Meets Initial Values (As Above)	Remove from test chambe temperature for						
	Appearance	No visual defects							
	Capacitance Variation	≤ ±12.5%	Store in a test chamber se 5% relative humidity for 10						
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	rated voltage	e applied.					
,	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber a temperature and 24 ± 2 hours befo	humidity for					
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 Hours Dero						





### **PREFERRED SIZES ARE SHADED**

Case Size		01	01*			0201					04	02			0603 0805														
Soldering			v Only		Re	flow O	nlv			-		//Wav	e				Refl	ow/W						Ref	low/W				
Packaging		Paper/Er				II Pape						aper						II Pap					Paper/Embossed						
(L) Length	mm (in.)	0.40	$0.40 \pm 0.02$ $0.60 \pm 0.09$ $(0.016 \pm 0.0008)$ $(0.024 \pm 0.004)$							1.00 ± 0.20 (0.040 ± 0.008)						1.60 ± 0.20 (0.063 ± 0.008)						2.01 ± 0.20 (0.079 ± 0.008)							
W) Width	mm (in.)	0.20 : (0.008 ±				30 ± 0. 11 ± 0.			0.50 ± 0.20 (0.020 ± 0.008)									30 ± 0 31 ± 0				1.25 ± 0.20 (0.049 ± 0.008)							
(t) Terminal	mm (in.)	0.10 : (0.004 ±				15 ± 0. 06 ± 0.						± 0.15 ± 0.00						35 ± 0 14 ± 0							50 ± 0 20 ± 0				
Voltage:		6.3	10	4	6.3	10	16	25	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50	
Cap (pF) 100	101		В					Α																					
150	151		В					Α																					
220	221		В					Α						С															
330	331		В					Α						С															
470	471		В					Α						С															
680	681		В					Α						С															
1000	102		В				Α	Α						С															
1500	152	В	В				Α	Α						С															
2200	222	В	В			Α	Α	Α						С															
3300	332	В	В			Α	Α	Α						С															
4700	472	В	В			Α	Α	Α					С								G								
6800	682	В	В			Α	Α	Α					С								G								
Cap (µF) 0.01	103	В	В			Α	Α	Α					С						G	G	G								
0.015	150	В											С						G	G	G								
0.022	223	В			Α	Α	Α	Α				С	С						G	G	G							N	
0.033	333	В										С							G	G	G							N	
0.047	473	В			Α	Α	Α	Α				С	С						G	G	G							N	
0.068	689	В										С				ļ	ļ	_	G		G	<u> </u>			-			N	
0.1	104	В			Α	Α	Α	Α			С	С	С	С					G	G	G					N	N	N	
0.15	154	-								_				-					G				_		_	N	N	L	
0.22	224	В		Α	Α	Α				С	С	С	С	С				G	G							N	N	N	
0.33 0.47	334 474	В		Α	Α	_			_	_	_	_	0	E	-	-	-	G	G		<u> </u>	_	-		-	N	P	P	
0.47	684	R		Α	Α				С	С	С	С	С	E		<u> </u>	-	G	J				-	-	-	N N	Р	Р	
1.0	105			Λ.	Α	С	С	-	С	С	С	С	С		G	G	G	G	J	G	G	_	-	-	N	N	P	Р	
1.0	155			Α	A	L	U		U	U	U	U	U		G	G	G	G	J	G	G				IN	IN	P P	P	
2.2	225			С	С	С	-	-	С	С	С	С	С		G	G	J	J	J	К	K		-	N	N	Р	Р	Р	
3.3	335			U	U	U	_	_	U	U	U	U	U		J	J	J	J	J		N.		N	N	IN	P	Р	Р	
4.7	475			С	С		_		Е	Е	Е	Е		_	J	J	J	G	K		-	N	P	J	N	N	Р	Р	
10	106								E	E	E				K	J	K	K	K			P	P	P	P	P		P	
22	226				<del>                                     </del>		<del>                                     </del>		E	G			+		K	K	K	IX	IX			P	P	P	P	P		1	
47	476			<u> </u>			_	<u> </u>		G			<del>                                     </del>		K	K	IX			<b>-</b>		P	P	P				<del>                                     </del>	
100	107				<del>                                     </del>	-	<del>                                     </del>			-	-	<del>                                     </del>	+		IX	IX	-		-				-		<del>                                     </del>	<u> </u>		+	
Voltage:	107	6.3	10	4	6.3	10	16	25	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50	
Case Size			01*		0.0	0201				0.0		02		1 00		0.0		0603		- 00	00	0805							
Out Size		J.				3201						-						3000							3000				

Letter	Α	В	С	E	G	J	K	М	N	Р	Q	Х	Υ	Z
Max. Thickness	0.33 (0.013)	0.22 (0.009)	0.56 (0.022)	0.71 (0.028)	0.90 (0.035)	0.94 (0.037)	1.02 (0.040)	1.27 (0.050)	1.40 (0.055)	1.52 (0.060)	1.78 (0.070)	2.29 (0.090)	2.54 (0.100)	2.79 (0.110)
			PAI	PER						EMBO	SSED			

PAPER and EMBOSSED available for 01005 NOTE: Contact factory for non-specified capacitance values \*EIA 01005





### **PREFERRED SIZES ARE SHADED**

Case Size					1206							1210				1812									
Soldering					ow/W							flow C							flow O						
Packaging				Paper			ŀ					/Emb							Embos						
(L) Length	mm (in.)				20 ± 0. 26 ± 0.				3.20 ± 0.40 (0.126 ± 0.016)								4.50 ± 0.30 (0.177 ± 0.012)								
W) Width	mm (in.)			1.6	0 ± 0.	.30					2.5	50 ± 0.	.30					3.2	20 ± 0. 26 ± 0.	.20					
	mm				$50 \pm 0.0$				(0.098 ± 0.012) 0.50 ± 0.25																
(t) Terminal	(in.)				20 ± 0.							20 ± 0				0.61 ± 0.36 (0.024 ± 0.014)									
Voltage:	, ,	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50			
Cap (pF) 100	101																								
150	151																								
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0.1	104																								
0.15	154																								
0.22	224																								
0.33	334																								
0.47	474					Q	Q							Х	Χ										
0.68	684																								
1.0	105					Q	Q	Q					Χ	Х	Х										
1.5	155																								
2.2	225			Q	Q	Q	Q	Q					Χ	Z	Z										
3.3	335		Q	Q																					
4.7	475	Χ	Х	Х	Х	Х	Х	Χ			Z	Z	Z	Z	Z										
10	106	Χ	Х	Х	Х	Х	Χ	Χ		Χ	Х	Z	Z	Z	Z					Z					
22	226	Χ	Х	Х	Х	Х			Z	Z	Z	Z	Z			Z	Z	Z	Z						
47	476	Χ	Х	Х	Х				Z	Z	Z	Z	Z												
100	107	Χ	Х						Z	Z															
Voltage:		4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50			
Case Size					1206							1210				1812									

Letter	Α	В	С	E	G	J	K	М	N	P	Q	X	Υ	Z
Max.	0.33	0.22	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.009)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PA	PER						ЕМВО	SSED			

PAPER and EMBOSSED available for 01005

NOTE: Contact factory for non-specified capacitance values \*EIA 01005

